## 1 Product profile

### 1.1 General description

Quad PIN diode in a SOT753 package.

#### 1.2 Features and benefits

- 4 PIN diodes in a SOT753 package
- 300 kHz to 4 GHz
- High linearity
- · Low insertion loss
- reduction in part count
- · Low diode capacitance
- · Low diode forward resistance

### 1.3 Applications

- RF attenuators
- Broadband system applications
- General-purpose Voltage Controlled Attenuators for high linearity applications



Quad PIN diode attenuator

## 2 Pinning information

Table 1. Discrete pinning

| Pin | Description  | Simplified outline | Graphic symbol |  |  |  |  |
|-----|--------------|--------------------|----------------|--|--|--|--|
| 1   | RF in        | П- П.              |                |  |  |  |  |
| 2   | series bias  | 5 -4               | 5 4            |  |  |  |  |
| 3   | RF out       |                    |                |  |  |  |  |
| 4   | shunt 1 bias | 1 2 3              | 1 2 3          |  |  |  |  |
| 5   | shunt 2 bias | Top view           | sym143         |  |  |  |  |

## 3 Ordering information

**Table 2. Ordering information** 

| Type number Package                   |        |  |         |  |  |
|---------------------------------------|--------|--|---------|--|--|
| , , , , , , , , , , , , , , , , , , , | Name   | Description                              | Version |  |  |
| BAP64Q                                | SC-74A | plastic surface-mounted package; 5 leads | SOT753  |  |  |

## 4 Marking

Table 3. Marking

| Type number | Marking code |
|-------------|--------------|
| BAP64Q      | A1           |

## 5 Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter               | Conditions              |     | Min | Max  | Unit |
|------------------|-------------------------|-------------------------|-----|-----|------|------|
| $V_{R}$          | reverse voltage         |                         | [1] | -   | 100  | V    |
| I <sub>F</sub>   | forward current         |                         | [1] | -   | 100  | mA   |
| P <sub>tot</sub> | total power dissipation | T <sub>sp</sub> ≤ 90 °C | [1] | -   | 125  | mW   |
| T <sub>stg</sub> | storage temperature     |                         |     | -65 | +150 | °C   |
| Tj               | junction temperature    |                         |     | -65 | +150 | °C   |

<sup>[1]</sup> single diode.

### 6 Thermal characteristics

**Table 5. Thermal characteristics** 

| Symbol         | Parameter  | Conditions | Тур | Unit |
|----------------|--|------------|-----|------|
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point |            | 350 | K/W  |

BAP64Q

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**Quad PIN diode attenuator** 

### 7 Characteristics

**Table 6. Characteristics** 

 $T_i$  = 25 °C unless otherwise specified.

| Symbol  | Parameter                | Conditions  |     | Min | Тур  | Max  | Unit |
|---|--------------------------|---|-----|-----|------|------|------|
| Per diod  | e                        |   |     |     |      | -    |      |
| V <sub>F</sub>  | forward voltage          | I <sub>F</sub> = 50 mA  |     | -   | 0.95 | 1.1  | V    |
| I <sub>R</sub>  | reverse current          | V <sub>R</sub> = 60 V   |     | -   | -    | 10   | μΑ   |
|   |                          | V <sub>R</sub> = 20 V   |     | -   | -    | 1    | μΑ   |
| C <sub>d</sub> diode capacitance f = 1 MHz (see <u>Figure 1</u> ) |                          |   |     |     |      |      | -    |
|   |                          | V <sub>R</sub> = 0 V  |     | _   | 0.52 | -    | pF   |
|   |                          | V <sub>R</sub> = 1 V  |     | -   | 0.37 | -    | pF   |
|   |                          | V <sub>R</sub> = 20 V   |     | -   | 0.23 | 0.35 | pF   |
| r <sub>D</sub>  | diode forward resistance | f = 100 MHz (see Figure 2)  |     |     |      |      | ,    |
|   |                          | I <sub>F</sub> = 0.5 mA   | [1] | -   | 20   | 40   | Ω    |
|   |                          | I <sub>F</sub> = 1 mA   | [1] | -   | 10   | 20   | Ω    |
|   |                          | I <sub>F</sub> = 10 mA  | [1] | -   | 2    | 3.8  | Ω    |
|   |                          | I <sub>F</sub> = 100 mA   | [1] | -   | 0.7  | 1.35 | Ω    |
| τι  | charge carrier life time | when switched from $I_F$ = 10 mA to $I_R$ = 6 mA; $R_L$ = 100 $\Omega$ ; measured at $I_R$ = 3 mA |     | -   | 1.55 | -    | μs   |

<sup>[1]</sup> Guaranteed on AQL basis: inspection level S4, AQL 1.0.

### **Quad PIN diode attenuator**

## 8 Graphical data

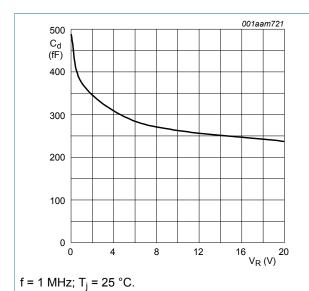
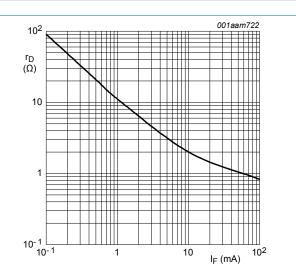


Figure 1. Diode capacitance as a function of reverse voltage (typical values)



f = 100 MHz;  $T_j = 25 \,^{\circ}\text{C}$ .

Figure 2. Diode forward resistance as a function of forward current (typical values)

**Quad PIN diode attenuator** 

## 9 Application information

### 9.1 Application circuit

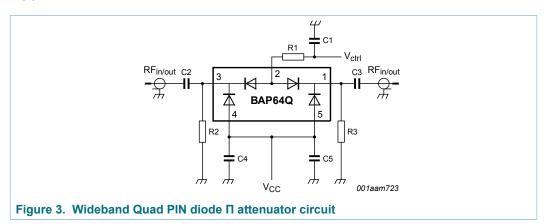


Table 7. List of components used for the typical application

| Component          | Description    | Value  |
|--------------------|----------------|--------|
| C1; C2; C3; C4; C5 | chip capacitor | 10 nF  |
| R1; R2; R3         | chip resistor  | 1000 Ω |

### 9.2 Quad PIN Π attenuator characteristics

Table 8. Typical performance for BAP64Q quad PIN diode Π attenuator

 $V_{CC}$  = 0.75 V;  $T_{amb}$  = 25 °C unless otherwise specified.

| Symbol           | Parameter                         | Test Conditions                     | Тур | Units |
|------------------|-----------------------------------|-------------------------------------|-----|-------|
| L <sub>ins</sub> | insertion loss                    | V <sub>ctrl</sub> = 10 V; f = 1 GHz | 1.8 | dB    |
| RLin             | input return loss                 | V <sub>ctrl</sub> = 0 V; f = 1 GHz  | 18  | dB    |
| α                | attenuation                       | V <sub>ctrl</sub> = 0 V; f = 1 GHz  | 38  | dB    |
| IP3 <sub>i</sub> | input third-order intercept point | f = 0.1 GHz                         |     |       |
|                  |                                   | V <sub>ctrl</sub> = 2 V             | 32  | dBm   |
|                  |                                   | V <sub>ctrl</sub> = 10 V            | 42  | dBm   |
|                  |                                   | f = 0.9 GHz                         |     |       |
|                  |                                   | V <sub>ctrl</sub> = 2 V             | 40  | dBm   |
|                  |                                   | V <sub>ctrl</sub> = 10 V            | 41  | dBm   |
|                  |                                   | f = 1.8 GHz                         |     |       |
|                  |                                   | V <sub>ctrl</sub> = 2 V             | 40  | dBm   |
|                  |                                   | V <sub>ctrl</sub> = 10 V            | 37  | dBm   |
|                  |                                   | f = 2.1 GHz                         | '   |       |
|                  |                                   | V <sub>ctrl</sub> = 2 V             | 38  | dBm   |
|                  |                                   | V <sub>ctrl</sub> = 10 V            | 39  | dBm   |

### **Quad PIN diode attenuator**

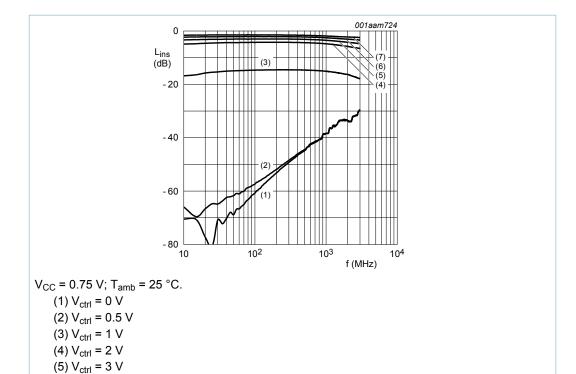


Figure 4. Insertion loss as function of frequency (typical values)

(6)  $V_{ctrl} = 5 V$ (7)  $V_{ctrl} = 10 V$ 

80

60

20

(2)

(3) 40

(4)

α

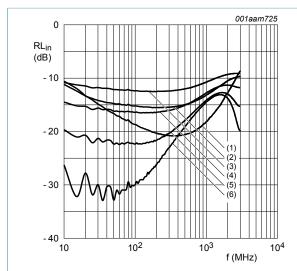
(dB)

001aam726

102

V<sub>ctrl</sub> (V)

10



 $V_{CC}$  = 0.75 V;  $T_{amb}$  = 25 °C.

(1) 
$$V_{ctrl} = 0 V$$

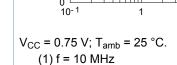
(2) 
$$V_{ctrl} = 1 V$$

(3) 
$$V_{ctrl} = 2 V$$

(4) 
$$V_{ctrl} = 3 V$$

(5) 
$$V_{ctrl} = 5 V$$

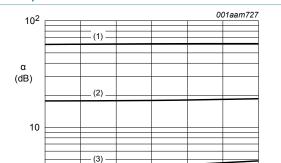
(6) 
$$V_{ctrl} = 10 V$$



(3) 
$$f = 1000 \text{ MHz}$$

(4) f = 3000 MHz

Figure 5. Return loss as function of frequency (typical values)



 $V_{CC} = 0.75 \text{ V}$ ; f = 100 MHz.

(4)

(5)

(6)

(1) 
$$V_{ctrl} = 0 V$$

(2) 
$$V_{ctrl} = 1 V$$

(3) 
$$V_{ctrl} = 2 V$$

(4) 
$$V_{ctrl} = 3 V$$
  
(5)  $V_{ctrl} = 5 V$ 

values)

40

T<sub>amb</sub> (°C)

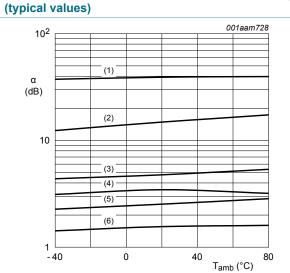


Figure 6. Attenuation as function of control voltage

 $V_{CC} = 0.75 \text{ V}$ ; f = 1000 MHz.

(1) 
$$V_{ctrl} = 0 V$$

(2) 
$$V_{ctrl} = 1 V$$

(3) 
$$V_{ctrl} = 2 V$$

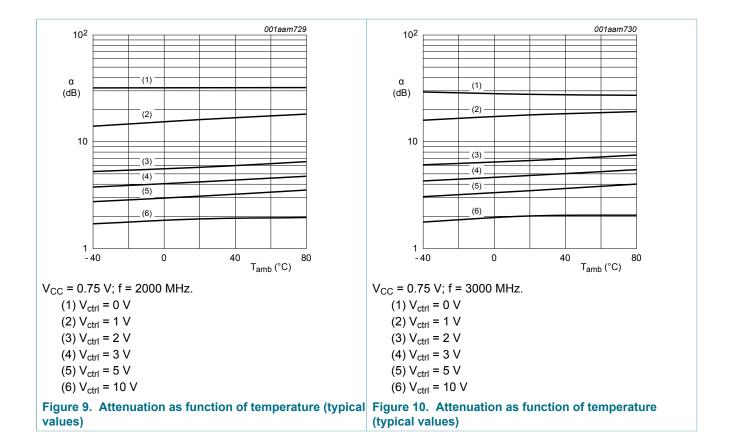
(4) 
$$V_{ctrl} = 3 V$$

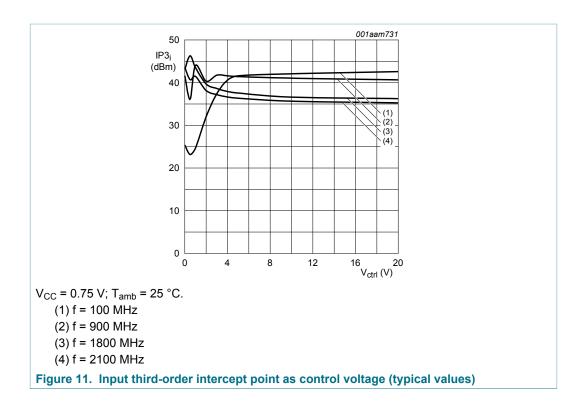
(5) 
$$V_{ctrl} = 5 V$$

(6) 
$$V_{ctrl} = 10 \text{ V}$$

Figure 7. Attenuation as function of temperature (typical Figure 8. Attenuation as function of temperature (typical values)

#### **Quad PIN diode attenuator**





## 10 Package outline

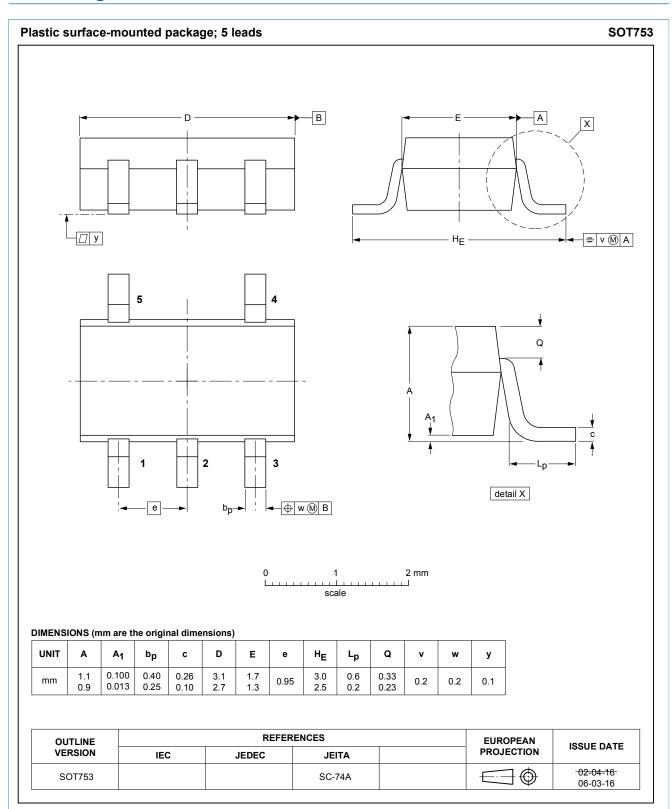


Figure 12. Package outline SOT753

**Quad PIN diode attenuator** 

### 11 Abbreviations

#### Table 9. Abbreviations

| Acronym | Description                |
|---------|----------------------------|
| AQL     | acceptable quality level   |
| PIN     | P-type, intrinsic, N-type  |
| RF      | radio frequency            |
| S4      | special inspection level 4 |

## 12 Revision history

### Table 10. Revision history

| Document ID    | Release date  | Data sheet status                            | Change notice    | Supersedes |  |
|----------------|---|--|------------------|------------|--|
| BAP64Q v.2.1   | 20190201  | Product data sheet                           | -                | BAP64Q v.2 |  |
| Modifications: | changed condition   | on for reverse current for V <sub>R</sub> fr | om 100 V to 60 V | '          |  |
| BAP64Q v.2     | 20181213  | Product data sheet                           | -                | BAP64Q v.1 |  |
| Modifications: | <ul> <li>The "Legal information" pages have been updated.</li> <li>Adjusted Limiting Value P<sub>tot</sub> to T<sub>sp</sub> ≤ 90 °C</li> </ul> |  |                  |            |  |
| BAP64Q v.1     | 20101007  | Product data sheet                           | -                | -          |  |

**Quad PIN diode attenuator** 

### 13 Legal information

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| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition  |
|-----------------------------------|-------------------------------|---|
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BAP64Q

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#### **Quad PIN diode attenuator**

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# **BAP64Q**

### Quad PIN diode attenuator

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